

2SD2702 / 2SD2674

NPN 1.5A 12V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	12V
I _C	1.5A

● Features

1) Suitable for Middle Power Driver

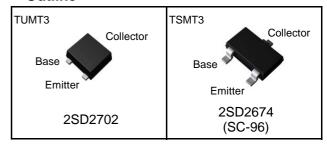
2) Complementary PNP Types: 2SB1732, 2SB1709

3) Low V_{CE}(sat)

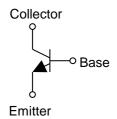
 $V_{CE}(sat)=0.20V(Max.)$ ($I_C/I_B=500mA/25mA$)

4) Lead Free/RoHS Compliant.

Outline



•Inner circuit



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SD2702	TUMT3	2021	TL	180	8	3,000	ES
2SD2674	TSMT3	2928	TL	180	8	3,000	ES

● **Absolute maximum ratings** (Ta = 25°C)

Parameter		Symbol	Values	Unit	
Collector-base voltage		V _{CBO}	15	V	
Collector-emitter voltage		V _{CEO}	12	V	
Emitter-base voltage		V _{EBO}	6	V	
Callagtor augreent	DC	I _C	1.5	А	
Collector current	Pulsed	I _{CP}	3*1	А	
	2SD2702	P _D	0.4	W	
Dower dissination	2302702	r _D	0.8 *2		
Power dissipation	2602674	В	0.5	W	
	2SD2674	P_{D}	1.0 *2		
Junction temperature		T _j	150	°C	
Range of storage tempera	ture	T _{stg}	−55 to +150	°C	

^{*1} Pw=1ms, single pulse

●Electrical characteristics(Ta = 25°C)

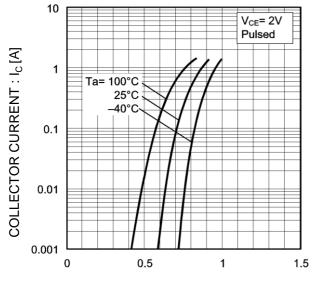
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CBO}	I _C = 10μA	15	ı	ı	V
Collector-base breakdown voltage	BV _{CEO}	I _C = 1mA	12	ı	ı	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = 10μA	6	ı	ı	V
Collector cut-off current	I _{CBO}	V _{CB} = 15V	-	-	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 6V	-	-	100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500 \text{mA}, I_B = 25 \text{mA}$	ı	85	200	mV
DC current gain	h _{FE} *3	$V_{CE} = 2V$, $I_C = 200$ mA	270	-	680	-
Transition frequency	f _T *3	$V_{CE} = 2V$, $I_{E} = -200$ mA f=100MH _Z	ı	400	ı	MHz
Output capacitance	C_{ob}	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$	ı	12	ı	pF

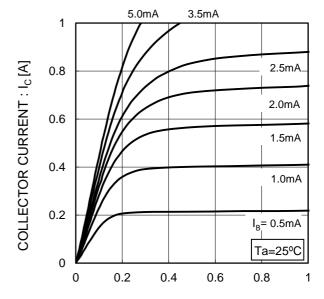
^{*3} Pulsed

^{*2} Mounted on a ceramic board (25x25x0.8 mm)

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics Fig.2 Typical Output Characteristics





BASE TO EMITTER VOLTAGE: VBE [V]

COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)

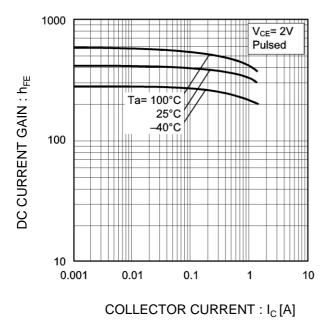
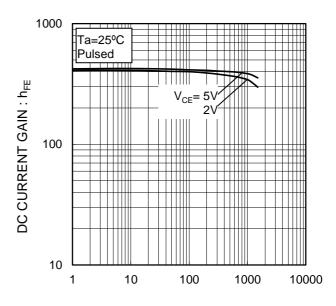


Fig.4 DC Current Gain vs. Collector Current(II)



COLLECTOR CURRENT : I_C [mA]

10

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

0.01

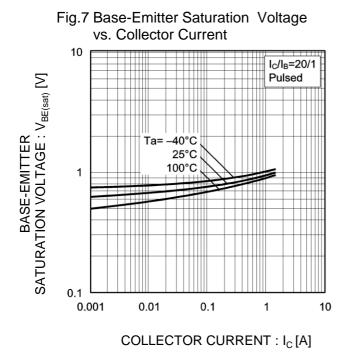
0.001

Fig.6 Collector-Emitter Saturation Voltage

COLLECTOR CURRENT : I_C[A]

COLLECTOR CURRENT : I_C[A]

0.1

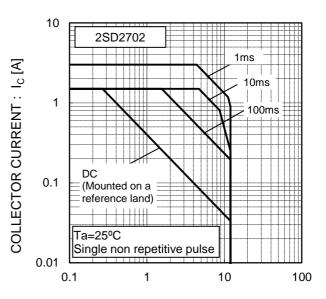


EMITTER CURRENT : IF [A]

●Electrical characteristic curves(Ta = 25°C)

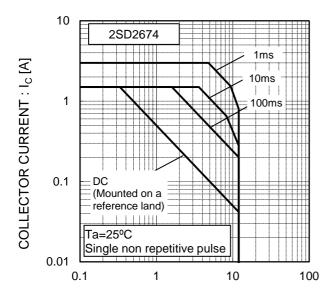
Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. Collector-Base Voltage COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF] 100 Ta= 25°C f=1MHz C_{ib} I_E=0A C_{ob} 10 0.1 10 100 $\begin{array}{c} \text{COLLECTOR - BASE VOLTAGE : V}_{\text{CB}} \left[\mathbf{V} \right] \\ \text{EMITTER - BASE VOLTAGE : V}_{\text{EB}} \left[\mathbf{V} \right] \end{array}$

Fig.10 Safe Operating Area



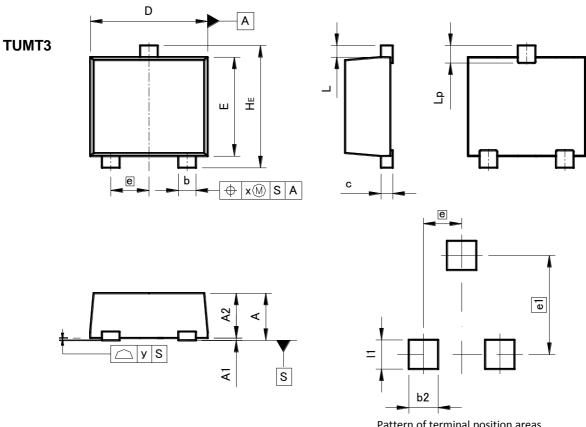
COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]

Fig.11 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}[V]$

●Dimensions (Unit : mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

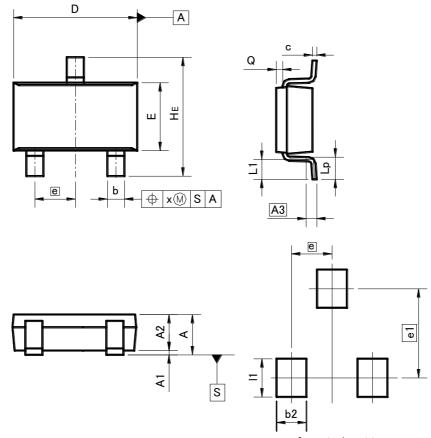
DIM MILIMETERS		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	ı	0.85	ı	0.033
A1	0.00	0.10	0.000	0.004
A2	0.72	0.82	0.028	0.032
b	0.25	0.40	0.010	0.016
С	0.12	0.22	0.005	0.009
D	1.90	2.10	0.075	0.083
Е	1.60	1.80	0.063	0.071
е	0.0	65	0.0	26
HE	2.00	2.20	0.079	0.087
L	0.3	.20 0.008		80
Lp	_	0.40	_	0.016
х	_	0.10	_	0.004
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES	
DIM	MIN MAX		MIN	MAX
b2	ı	0.50	_	0.020
e1	1.70		0.0	067
l1	- 0.50		_	0.020

Dimension in mm / inches

●Dimensions (Unit : mm)





Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	_	1.00	ı	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.5	25	0.0	10
b	0.35	0.50	0.014	0.020
С	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.9	95	0.0	37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
Х	_	0.20	_	0.008

DIM	MILIMETERS		INCHES	
DIIVI	MIN MAX		MIN	MAX
b2		0.70	_	0.028
e1	2.	2.10		83
l1	_	0.90	ı	0.035

Dimension in mm / inches

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